

## Layer-Oriented 2D Conjugated Metal-Organic Framework Films Enabling Directional Charge Transport

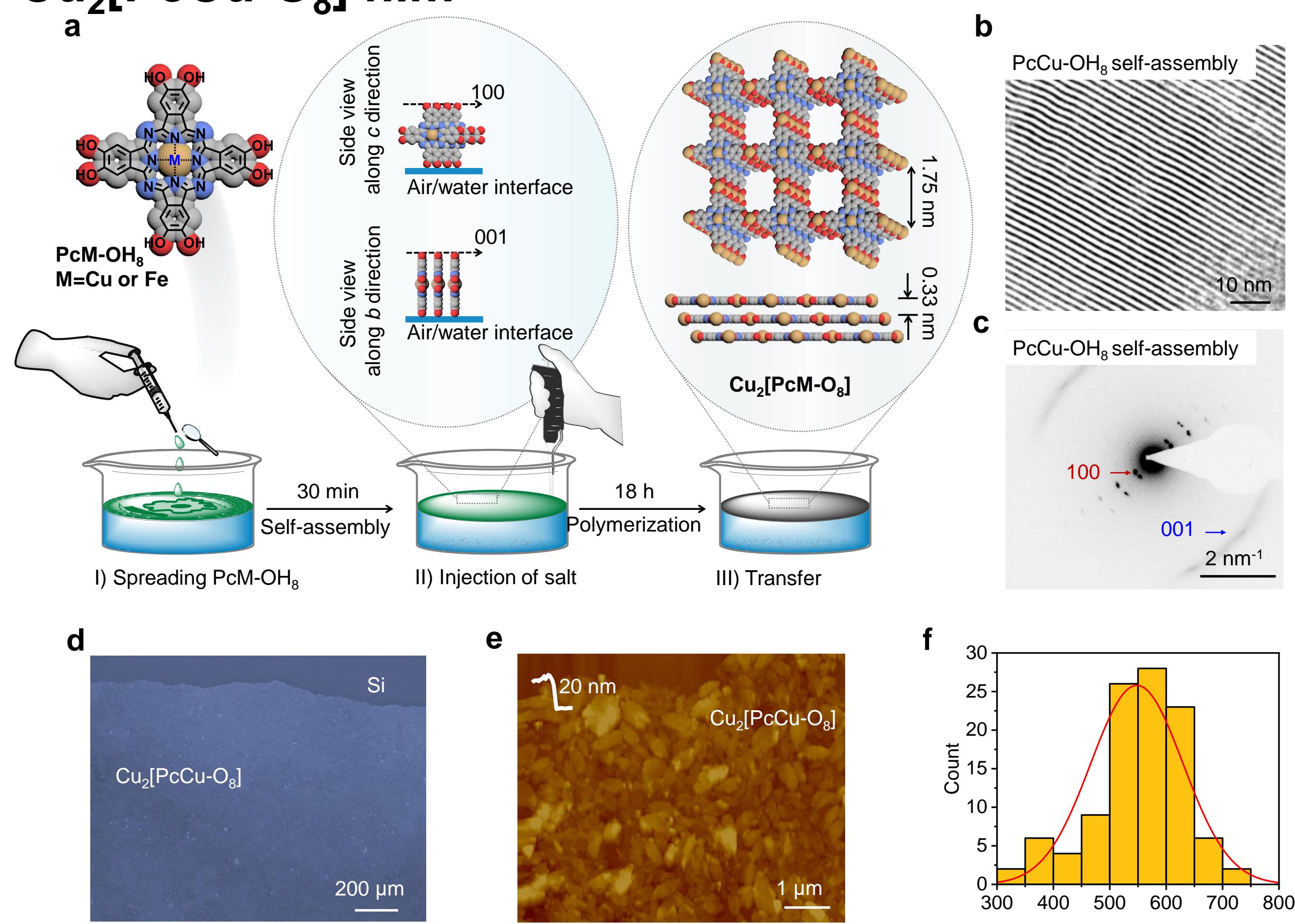
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### Abstract

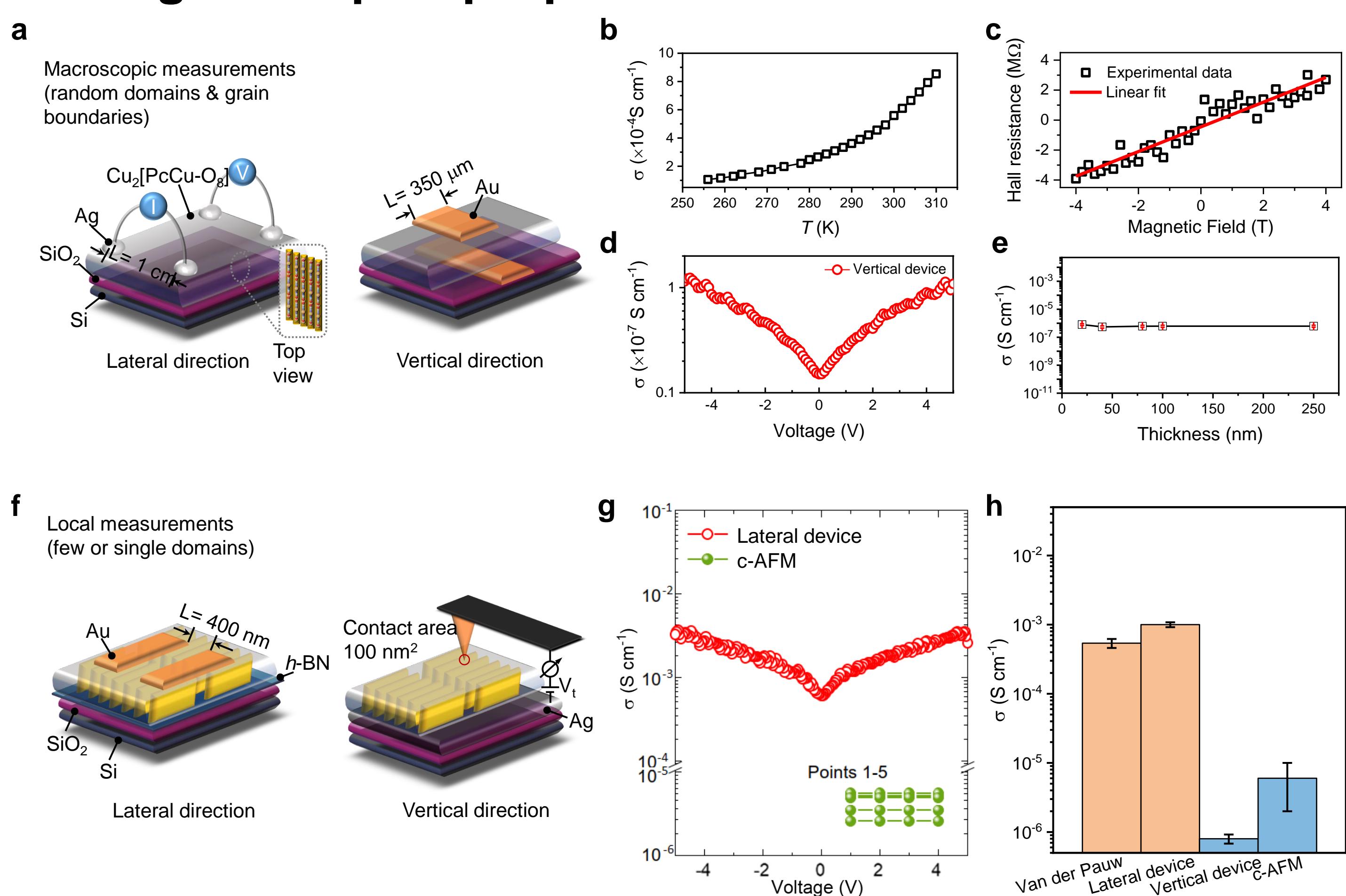
Edge-on layer-oriented *p*-type semiconducting 2D conjugated MOF (2D c-MOF) films comprising phthalocyanine ligands have been obtained at the air/water interface. The correlation between ligands and their alignment at the air/water interface was established. Macroscopic and local (sub- $\mu\text{m}$ ) charge transport measurements, combined with theoretical calculation have disclosed that the intrinsic conductivity is dominated by the charge transfer along the interlayer pathway.

### Synthesis and morphological characterization of the Cu<sub>2</sub>[PcCu-O<sub>8</sub>] film



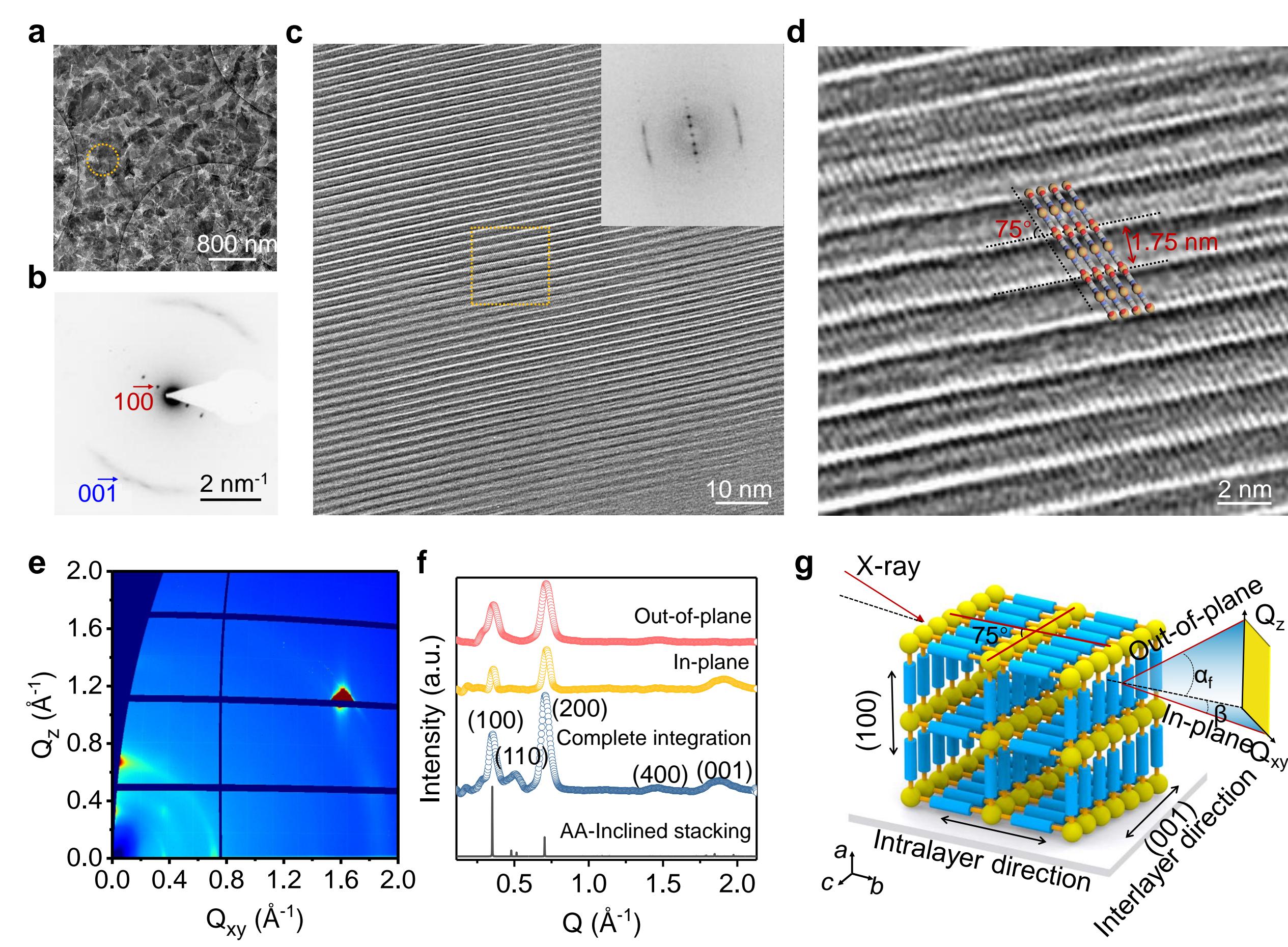
- π-π interaction and hydrophobicity guide the molecular arrangement and the edge-on structure formation of Cu<sub>2</sub>[PcCu-O<sub>8</sub>].
- Thickness 20 nm, domain size, ~ 600 nm.

### Charge transport properties



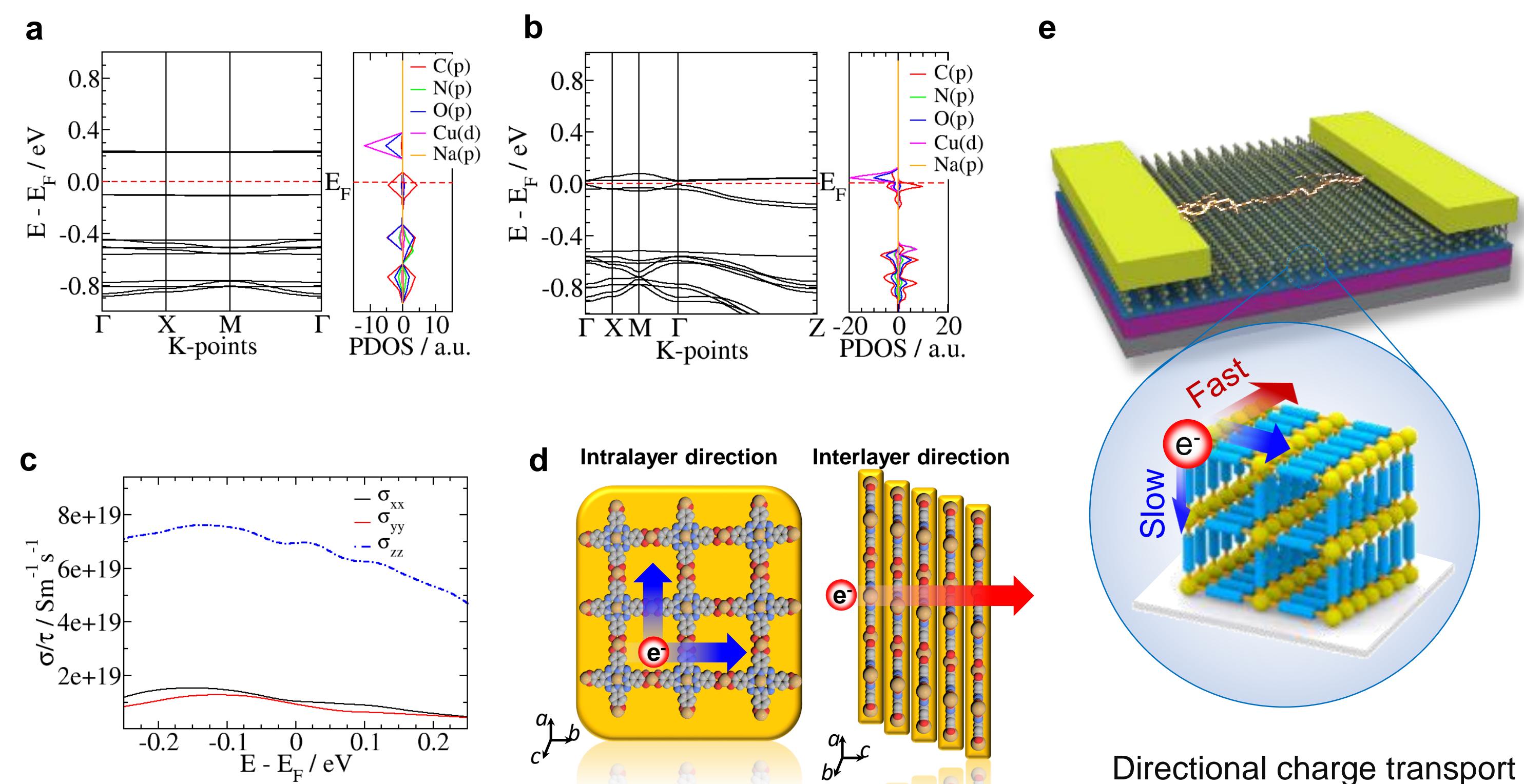
- Lateral direction: room-temperature mobility: ~ 4.4 cm<sup>2</sup> V<sup>-1</sup> s<sup>-1</sup>; Conductivity: 10<sup>-4</sup> ~ 10<sup>-3</sup> S cm<sup>-1</sup>.
- Vertical direction: Conductivity: 10<sup>-6</sup> ~ 10<sup>-5</sup> S cm<sup>-1</sup>.
- Such anisotropic behavior can be attributed to the preferential charge transport along the layer-stacking direction.

### Crystal structural characterization of Cu<sub>2</sub>[PcCu-O<sub>8</sub>]



- AC-HRTEM image presents highly ordered linear arrangement with a lattice distance of 1.80 nm and a interlayer distance of 0.33 nm.
- GIWAXS measurement demonstrates a preference of Cu<sub>2</sub>[PcCu-O<sub>8</sub>] for the edge-on orientation.

### Mechanism of directional charge transport property



- Conjugation direction: no dispersion in both conduction and valence bands near the Fermi level; band gap 0.35 eV.
- π-π stacking direction: Small band gap 0.03 eV; higher dispersion of the valence bands

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### REFERENCES

Z. Wang et al., *J. Am. Chem. Soc.* 2021, doi.org/10.1021/jacs.1c05051.